

High Triplet Energy n-type Dopants for High Efficiency in Phosphorescent OLEDs

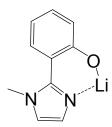
Product Specifications

LT-N896 Lilm Lithium 2-(1-methyl-1*H*-imidazol-2-yl)phenolate

CAS No.1646267-86-8GradeSublimed, >99 %Formula $C_{10}H_9LiN_2O$ Molecular Weight180.13 g/moleUV absorption262, 320, 341 nmPhotoluminescence387 nm (in CH $_2$ Cl $_2$)

Triplet Energy 2.82 eV

Reference: C.S. Oh, J.Y. Lee / Organic Electronics 16 (2015) 34–39



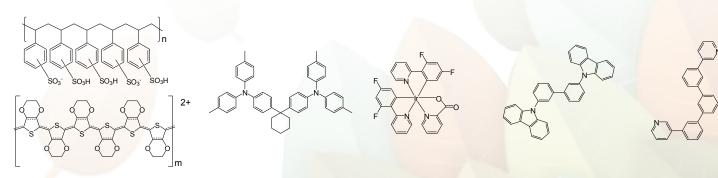
Features

- The Lilm with high triplet energy n-type dopant was effectively synthesized to increase the mobility (two order) of electron transport material and suppress triplet exciton quenching in blue PHOLEDs.
- The quantum efficiency of electron injection layer free PHOLEDs was improved by reduced triplet exciton quenching effect by Lilm compared to Liq.
- The high triplet energy n-type dopant can replace current Liq dopant and simplify the device structure by omitting an electron injection layer.

Device Application

The Blue Device:

ITO (50 nm)/ PEDOT:PSS (60 nm)/ TAPC (20 nm)/ mCBP:FIrpic (25 nm, 10% doping)/ BmPyPb:Lilm (40 nm)/ Al (200 nm). Related products from Lumtec :



LT-PS001 PEDOT:PSS

LT-N137 TAPC

LT-E607 FIrPic

LT-N4069 m-CBP

LT-N863 TmPyPB